DESCRIPTION

The SPN7402 is the N-Channel logic enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology.

This high density process is especially tailored to minimize on-state resistance.

These devices are particularly suited for low voltage application such as cellular phone and notebook computer power management and other battery powered circuits where high-side switching, and low in-line power loss are needed in a very small outline surface mount package.

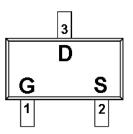
APPLICATIONS

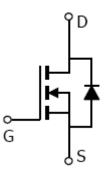
- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch
- DSC
- LCD Display inverter

FEATURES

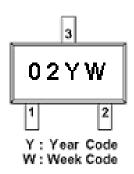
- 20V/4.0A, RDS(ON)= $65m\Omega(@VGS=4.5V)$
- \bullet 20V/3.4A,RDS(ON)=80m Ω @VGS=2.5V
- 20V/2.8A,RDS(ON)= $95m\Omega$ @VGS=1.8V
- ◆ Super high density cell design for extremely low RDS (ON)
- Exceptional on-resistance and maximum DC current capability
- ♦ SOT-323 (SC -70) package design

PIN CONFIGURATION (SOT-323; SC-70)





PART MARKING



PIN DESCRIPTION						
Pin	Symbol	Description				
1	G	Gate				
2	S	Source				
3	D	Drain				

ORDERING INFORMATION

Part Number	Package	Part Marking
SPN7402S32RGB	SOT-323	02

% Week Code : A ~ Z(1 ~ 26); a ~ z(27 ~ 52)

※ SPN7402S32RGB: Tape Reel; Pb − Free; Halogen − Free

ABSOULTE MAXIMUM RATINGS

(Ta=25°C Unless otherwise noted)

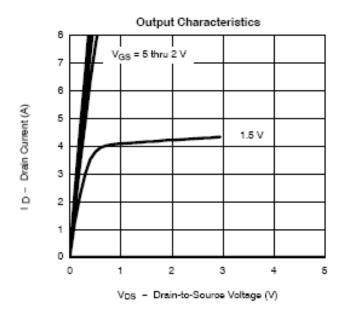
Parameter		Symbol	Typical	Unit	
Drain-Source Voltage		Vdss	20	V	
Gate –Source Voltage		VGSS	±12	V	
Continuous Drain Current(T1-150°C)	Ta=25°C	ID	2.4	A	
Continuous Drain Current(T _J =150°C)	Ta=70°C		1.7	A	
Pulsed Drain Current		Ірм	6	A	
Continuous Source Current(Diode Conduction)		Is	1.6	A	
Barran Dissipation	Ta=25°C	PD	0.33	11 7	
Power Dissipation	Ta=70°C		0.21	W	
Operating Junction Temperature		ιΤ	-55/150	°C	
Storage Temperature Range		Tstg	-55/150	°C	
Thermal Resistance-Junction to Ambient		RθJA	105	°C/W	

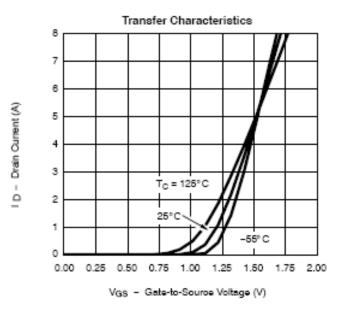
ELECTRICAL CHARACTERISTICS

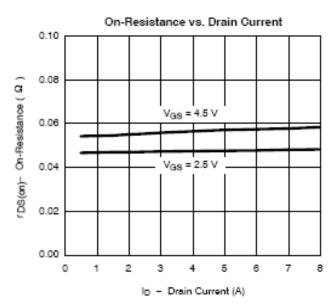
(Ta=25°C Unless otherwise noted)

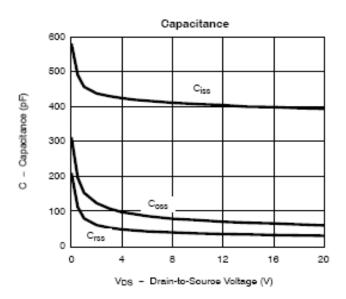
Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit	
Static	•						
Drain-Source Breakdown Voltage	V(BR)DSS	VGS=0V,ID=250uA	20			***	
Gate Threshold Voltage	VGS(th)	Vds=Vgs,Id=250uA	0.35		0.85	V	
Gate Leakage Current	Igss	VDS=0V,VGS=±12V			±100	nA	
Zero Gate Voltage Drain Current	IDSS	VDS=20V,VGS=0V VDS=20V,VGS=0V TJ=55°C			5	uA	
On-State Drain Current	ID(on)	$V_{DS} \leq 5V, V_{GS} = 4.5V$	6			A	
Drain-Source On-Resistance	RDS(on)	VGS=4.5V,ID=4.0A VGS=2.5V,ID=3.4A VGS=1.8V,ID=2.8A		0.060 0.067 0.076	0.065 0.080 0.095	Ω	
Forward Transconductance	gfs	VDS=5V,ID=-3.6A		10		S	
Diode Forward Voltage	Vsd	Is=1.6A,VGS=0V		0.8	1.2	V	
Dynamic							
Total Gate Charge	Qg			4.8	8	nC	
Gate-Source Charge	Qgs	VDS=6V,VGS=4.5V ID=2.8A		1.0			
Gate-Drain Charge	Qgd	-ID-2.0A		1.0			
Input Capacitance	Ciss			485		pF	
Output Capacitance	Coss	VDS=6V,VGS=0V f=1MHz		85			
Reverse Transfer Capacitance	Crss			40			
Turn-On Time	td(on)			8	14	nS	
	tr	$V_{DD}=6V,RL=6\Omega$		12	18		
Turn-Off Time	td(off)	ID=1.0A,VGEN=4.5V RG=6 Ω		30	35		
	tf	·		12	16		

TYPICAL CHARACTERISTICS

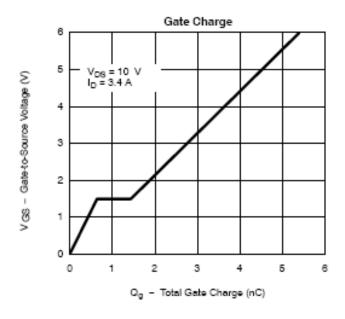


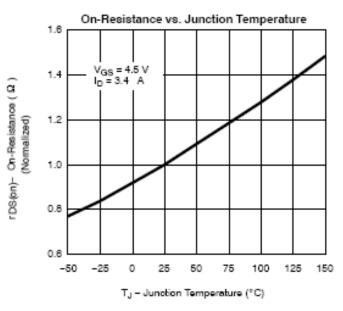


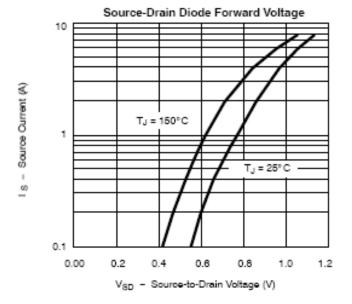


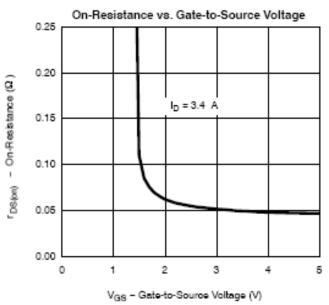


TYPICAL CHARACTERISTICS

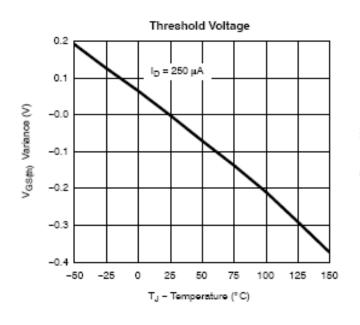


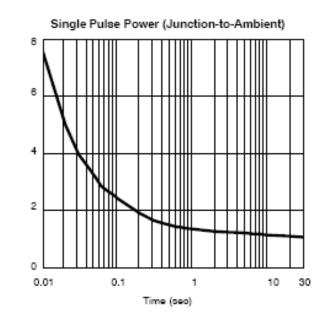


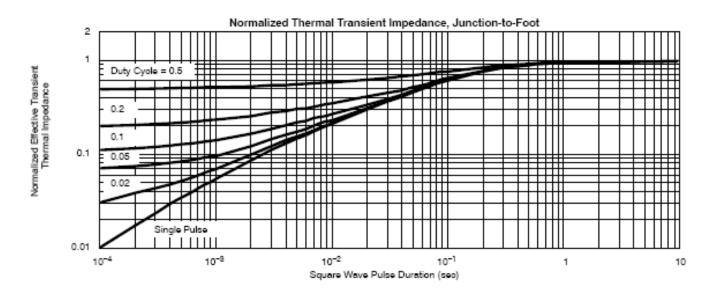




TYPICAL CHARACTERISTICS







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